Yuan, Qingchen; Fang, Liang; Zhao, Qiang; Wang, Yadong; Mao, Bo; Khayrudinov, Vladislav; Lipsanen, Harri; Sun, Zhipei; Zhao, Jianlin; Gan, Xuetao

Mode couplings of a semiconductor nanowire scanning across a photonic crystal nanocavity

Published in:
CHINESE OPTICS LETTERS

DOI:
10.3788/COL201917.062301

Published: 10/06/2019

Please cite the original version:
Yuan, Q., Fang, L., Zhao, Q., Wang, Y., Mao, B., Khayrudinov, V., Lipsanen, H., Sun, Z., Zhao, J., & Gan, X. (2019). Mode couplings of a semiconductor nanowire scanning across a photonic crystal nanocavity. CHINESE OPTICS LETTERS, 17(6), 62301. [062301]. https://doi.org/10.3788/COL201917.062301

This material is protected by copyright and other intellectual property rights, and duplication or sale of all or part of any of the repository collections is not permitted, except that material may be duplicated by you for your research use or educational purposes in electronic or print form. You must obtain permission for any other use. Electronic or print copies may not be offered, whether for sale or otherwise to anyone who is not an authorised user.
## Mode Couplings of a Semiconductor Nanowire Scanning across a Photonic Crystal Nanocavity

<table>
<thead>
<tr>
<th>Journal:</th>
<th><em>Chinese Optics Letters</em></th>
</tr>
</thead>
<tbody>
<tr>
<td>Manuscript ID</td>
<td>COL-19-0011</td>
</tr>
<tr>
<td>Manuscript Type:</td>
<td>Original</td>
</tr>
<tr>
<td>Date Submitted by the Author:</td>
<td>04-Jan-2019</td>
</tr>
<tr>
<td>Complete List of Authors:</td>
<td>Yuan 元晴晨, Qingchen Liang 方亮, Fang Zhao 赵强, Qiang Wang 王亚东, Yadong Mao 毛博, Bo Khayrudinov, Vladislav Lipsanen, Harri Sun 孙志培, Zhipei Zhao, Jianlin; 西北工业大学, 理学院 应用物理系 Gan, Xuetao; Northwestern Polytech Univ, physics</td>
</tr>
<tr>
<td>Keywords:</td>
<td>230.5298 Photonic crystals &lt; 230.0230 Optical devices, 160.4236 Nanomaterials &lt; 160.0160 Materials, 260.5740 Resonance &lt; 260.0260 Physical optics</td>
</tr>
<tr>
<td>Speciality:</td>
<td></td>
</tr>
</tbody>
</table>
Mode Couplings of a Semiconductor Nanowire Scanning across a Photonic Crystal Nanocavity

Qingchen Yuan (元晴晨)\textsuperscript{1} , Liang Fang (方 亮)\textsuperscript{1} , Qiang Zhao (赵 强)\textsuperscript{2} , Yadong Wang (王亚东)\textsuperscript{1} , Bo Mao (毛 博)\textsuperscript{1} , Vladislav Khayrudinov\textsuperscript{3} , Harri Lipsanen\textsuperscript{4} , Zhipeи Sun (孙志培)\textsuperscript{3,4} , Jianlin Zhao (赵建林)\textsuperscript{1,*} , and Xuetao Gan (甘雪涛)\textsuperscript{1,*}

\textsuperscript{1}1MOE Key Laboratory of Material Physics and Chemistry under Extraordinary Conditions, and Shaanxi Key Laboratory of Optical Information Technology, School of Science, Northwestern Polytechnical University, Xi’an 710072, China
\textsuperscript{2}Qian Xuesen Laboratory of Space Technology, China Academy of Space Technology, Beijing 100094, China
\textsuperscript{3}3Department of Electronics and Nanoengineering, Aalto University, Espoo, FI-00076, Finland
\textsuperscript{4}4QTF Centre of Excellence, Department of Applied Physics, Aalto University, Espoo, FI-00076, Finland

*Corresponding author: jzhao@nwpu.edu.cn; xuetaogan@nwpu.edu.cn

Received xxxxx; accepted xxxxx; posted online xxxx

OCIS codes: 230.5298, 160.4236, 260.5740.
doi: xxxxxxx/COLxxxxxxx.

Semiconductor nanowires (NWs) have emerged as an important building block for nanoscale photonics and optoelectronics due to their strong quantum confinement effects of charge carriers, exotic excitons, high refractive indices, etc\textsuperscript{[1-3]}. A variety of NW-based active photonic devices have been developed, including low-threshold nanolasers\textsuperscript{[4]}, nano-LEDs\textsuperscript{[5,6]}, high-sensitive photodetectors\textsuperscript{[7-9]}, solar cells\textsuperscript{[10-12]}, and even multifunctional sensors\textsuperscript{[13]}. Unfortunately, most of these active devices were implemented in a configuration that NWs were surface-illuminated by vertically single-passed light beams. It is a challenge to couple light into NWs effectively considering their nanometric cross-section, which hinders the improvements of device performances. Constructing nanophotonic structures consisted of NWs to assist light-NW coupling are desired.

Recently, planar photonic crystal (PPC) nanocavities have attracted great interests to integrate semiconductor NWs for enhancing their light-matter interactions and constructing optoelectronic devices. For instance, the first NW laser at the telecom-band was realized by integrating an InP NW onto a silicon PPC nanocavity\textsuperscript{[14]}. This geometry also enables a microwatts continuous-wave pumped second harmonic generations in an AlGaAs NW\textsuperscript{[15]}. Comparing to other optical cavities, the transverse confinements of resonant modes in PPC nanocavities are provided by the photonic bandgap of the periodic air-holes, promising the design of nanoscale cavities with high quality (Q) factors\textsuperscript{[16]}. It facilitates the resonant modes to have extremely high ratios of Q factor to mode volume (V\textsubscript{mode}), which provides strongly localized optical fields. The nanoscale mode distribution also enables its effective overlap with NWs. In the vertical direction of the PPC nanocavities, the resonant modes are confined via the total internal reflection of the subwavelength-thick slab. The combination of modes’ high densities of electrical fields and their effective evanescent-couplings with NWs indicate the NW-PPC nanocavity could represent a reliable configuration to enhance light-NW interactions. In addition, PPCs have planar geometries for constructing NW-based optoelectronic devices, including laser diodes, photodetectors and electro-optical modulators\textsuperscript{[14,17,18]}

With the developed growth techniques of semiconductor NWs, it is possible to integrate them onto PPC nanocavities via transfer-manipulation process or in-situ growth\textsuperscript{[15,19,20]}. Because NWs’ cross-sections and PPC nanocavities are both in the nanoscale, their spatial alignments would significantly determine the light-NW coupling strengths. On the other hand, a NW would break cavity’s vertical total internal reflection due to NW’s high refractive index, which might degrade the cavity’s quality via the scattering loss. This extra scattering loss would lower the mode’s density of optical field as well as the light-NW interaction strength. A tradeoff between the mode-NW coupling strength and mode quality should be considered carefully in the NW-PPC nanocavity integration.
We herein study the varied mode-couplings of a NW by scanning it across a PPC nanocavity and discuss the optimal NW location for the effective light-NW interaction. The variations of resonant wavelength ($\Delta \lambda$), Q factors and the mode coupling efficiencies ($\eta$) are calculated when the NW is located at different positions, which indicate the strength of mode-NW couplings and light-NW interactions.

![Figure 1](image_url)

**Fig. 1.** (a) Schematic diagrams of a NW scanned across a PPC nanocavity along the lattice’s $\Gamma$ – M direction. (b) Intensity distribution of cavity’s fundamental mode. (c) $\Sigma P_x$, $\Delta \lambda$, and $\eta$ of the NW-PPC nanocavity versus NW’s positions. (d) $Q$ factor, $V_{mode}$, and $\eta Q/V_{mode}$ of NW-PPC nanocavity versus NW’s positions, where the red dashed lines indicate $Q_0$ and $V_{Mode0}$ of the bare nanocavity.

Figure 1(a) shows a NW scanned across a PPC nanocavity along the lattice’s $\Gamma$ – M direction. The coordinate system in the simulation model is displayed as well, which has an origin at the center of the cavity. The x and y-axis correspond to the lattice’s $\Gamma$ – M and M – K directions, respectively. Here, a H0 PPC nanocavity is employed, which is formed by shifting the four adjacent air-holes outwards\[^{[21]}\]. Comparing to PPC cavities with missing air-holes, the H0 PPC nanocavity has much smaller mode distribution and high Q factor\[^{[21]}\], allowing more effective light-NW couplings. The PPC is designed in a 220 nm thick slab with hexagonal lattice of air-holes. The lattice constant is about $a = 450 \text{ nm}$ and the air-hole radius is $r = 0.28a$. In the cavity defect region, the four adjacent air-holes are shifted by $S_x=0.2a$ in $x$-direction and $S_y=0.1a$ in $y$-direction, which enables high-Q resonant modes around the telecom-band. A NW is then integrated onto the H0 PPC nanocavity, where the NW is a standard cylinder with a length of $\sim 6 \mu \text{m}$ and a diameter of $\sim 100 \text{ nm}$. The resonant modes of the integrated nanocavity are numerically simulated using a finite element technique (COMSOL Multiphysics). To be consistent with the experimentally fabricated device, the materials for the PPC nanocavity and NW are chosen as silicon and AlGaAs in the simulation model, which have refractive indices of $\sim 3.48$ and $\sim 3.0$, respectively\[^{[15]}\].

![image](image_url)

Before the NW’s integration, the fundamental resonant mode of the bare PPC nanocavity is obtained at the wavelength of $\lambda_0 = 1555.9 \text{ nm}$ with the $Q_0$ factor of $\sim 5,600$ and $V_{Mode0}$ of 0.218 ($\lambda_0/n)^3$, where $n$ is the refractive index of silicon. The intensity profile is displayed in Fig. 1(b). The ultracompact mode mainly distributes over two and three lattices along the y- and x-directions, respectively. Because the NW only contacts with the evanescent field of the cavity mode, NW’s integration could be considered as a small perturbation to the resonant mode. According to the perturbation theory of the electromagnetic mode\[^{[16]}\], the scanned NWs then induce shifts of the resonant wavelength ($\Delta \lambda$), which is described by

$$
\Delta \lambda = \frac{\lambda_0}{2} \iiint \Delta \epsilon(x,y,z) |E|^2 \, dx \, dy \, dz + O(\Delta \epsilon^2(x,y,z)),
$$

(1)

Here, $E$ is the electric field of resonant mode for the unperturbed (bare) PPC nanocavity, and $\Delta \epsilon(x,y,z)$ is the NW-induced variation of the dielectric function. Hence, for resonant modes of the bare PPC nanocavity, it is worth calculating the optical power that would overlap with the NW, which indicates the mode-NW coupling strength. For the case that the NW is scanned along the $x$-direction ($\Gamma$ – $M$ direction), considering the NW’s one-dimensional structure, we calculate the optical power overlapping with the NW at different $x$-positions $\Sigma P_x$, as shown in the top panel of Fig. 1(c). It has the same trend as the mode distribution in Fig. 1(b).

After integrating the NW onto PPC nanocavity, the representative parameters, including $\Delta \lambda$, $Q$ factor, and $V_{mode}$ of the abovementioned resonant mode undergo significant changes when the NW scans to different $x$-positions across the cavity’s center. In the middle panel of Fig. 1(c), we plot the $\Delta \lambda$s versus the NW’s positions. The resonant wavelengths all undergo red-shifts in comparison with that of the bare PPC nanocavity, which is consistent with the perturbation theory of Eq. (1) and $\Sigma P_x$ distribution shown in the top panel of Fig. 1(c). And $\Delta \lambda$ has the largest value of 11.15 nm at $x = 180 \text{ nm}$, where the NW overlaps with the maximum node of the resonant mode. At the cavity’s center ($x = 0 \text{ nm}$), the weak coupling between NW and optical power of the resonant mode only causes a $\Delta \lambda = 1.95 \text{ nm}$. In the simulated modes of the integrated NW-PPC nanocavity, we could extract the mode-NW coupling efficiency $\eta$ directly by calculating the ratio of the optical power in the NW to that in the whole mode, i.e.,

$$
\eta = \frac{\int \int \int_{NW} |E|^2 \, dV}{\int \int \int |E|^2 \, dV},
$$

(2)

The bottom panel of Fig. 1(c) plots the calculated result. While the NWs at different positions perturb the cavity mode differently, the position-dependent $\eta$ has the same trend as the variation of $\Sigma P_x$ calculated from the bare cavity, which is shown in the top panel of Fig. 1(c). In brief, the most effective mode-NW coupling takes place at the positions that the optical power of the mode is maximum.

To employ an optical cavity to enhance light-NW interaction, there are some other figure of merit should be considered besides the mode-NW coupling...
efficiency $\eta$. For instance, resonant mode’s $Q$ factor and $V_{\text{mode}}$ imply the lifetime and spatial density of photons in the cavity, respectively. The intensity of the cavity mode is proportional to the factor of $Q/V_{\text{mode}}$, which determines the light-NW interaction strength as well. We calculate the variations of the $Q$ factor and $V_{\text{mode}}$ for the NW-PPC nanocavities with different NW positions, as shown in the top and middle panels of Fig. 1(d), respectively. The red dashed lines indicate the original $Q_0$ factor and $V_{\text{mode}0}$ of the bare nanocavity. Due to the NW’s high refractive index of $\sim 3.0$ and the broken geometry symmetry, the integration of NW would cause scattering loss for the resonant modes, which decrease the $Q$ factor. The degraded $Q$ factors have an opposite trend to the mode-NW coupling strength. When the NW locates at the cavity center, the $Q$ factor has the largest value of 5,100 due to the NW’s less perturbation. Over the region where the optical power of the mode is large ($x = 180$ nm), the $Q$ factor decreases to values of $\sim 250$. As will be discussed later, at this position, the NW induces an asymmetric mode distribution, which therefore yields more scattering loss. Scanning the NW to different positions also varies the $V_{\text{mode}}$ of the NW-PPC nanocavity between 0.210($\lambda/n)^3$ and 0.239($\lambda/n)^3$, as shown in the middle panel of Fig. 1(d). Similar as the variations of the $Q$ factors, the $V_{\text{mode}}$ has less change when the NW locates around the cavity’s center, and increases significantly when the NW close to the mode’s maximum node. It could be attributed to the penetration of optical field into the NW. However, when the NW moves outwards further, $V_{\text{mode}}$ decreases to values smaller than that of the bare cavity. To explain this variation, we display the simulated resonant modes of the NW-PPC nanocavity with the NW at the characteristic positions in Fig. 2. When the NW locates at $x = 360$ and 540 nm, the existence of NW reshapes the resonant mode to induce more optical field into the air-holes, which therefore results in smaller $V_{\text{mode}}$. In the NW-PPC nanocavity, the optical intensity interacting with the NW is proportional to the mode’s $Q/V_{\text{mode}}$ factor, which is important for the NW-based electro-optic effect, nonlinear effect, Purcell effect and etc [22, 23]. Another factor determining the light-NW interaction is the portion of the resonant mode coupled with the NW, i.e., $\eta$. We therefore would define the figure of merit to describe the light-NW interaction in the PPC nanocavity as $\eta Q/V_{\text{mode}}$. Its function of the $x$-positions is plotted in the bottom panel of Fig. 1(d). To employ a PPC nanocavity to enhance the light-NW interaction, the optimal position of the NW is the cavity center, while the mode-NW coupling is strongest when the NW overlaps with the mode’s maximum node, i.e., $x = 180$ nm.

Figure 2 displays the mode’s $x$-$y$ plane distribution of the NW-PPC nanocavities at the $z = 160$ nm, which is the plane through the NW’s center and actually shows the cavity’s evanescent field. These mode distributions could facilitate further explanations of the above results about the position-dependent $\Delta \lambda$, $Q$, $V_{\text{mode}}$, and $\eta$. According to the mode-NW coupling results shown in Figs. 1(c) and (d), the NW’s positions are chosen as $x = 0$ nm, 180 nm, 360 nm, and 540 nm to represent the special characteristics. In the intensity distributions shown in Figs. 2(a) and (c), the optical fields in the NW are almost null, i.e., the mode couples into the NW weakly. Hence, the $\Delta \lambda$ is less for these two cases. At the plane above the silicon slab, since less evanescent field is coupled into the NW, the mode is confined better by the total internal reflection, enabling high $Q$ factor. For the cases of Figs. 2(b) and (d), more optical fields are confined into the NW, which therefore give rise to higher mode-NW coupling and lower $Q$ factor. The varied mode-coupling behaviors of the NW at the four different positions are determined by the polarizations of the mode’s electrical fields. We denote the in-plane directions of the electrical field components, $E_x$ and $E_y$, using pink arrows. The density and length of the arrows imply the amplitude of the electrical fields distribution. For the NW’s positions at $x = 0$ nm and 360 nm, the electrical fields are mainly perpendicular to the NW, as shown in Figs. 2(a) and (b). According to the continuous boundary condition of the electromagnetic field, these perpendicular electrical fields are difficult to couple into the NW due to its high refractive index [7]. In contrast, when the NW moves to $x = 180$ nm and 540 nm, the mode’s electrical fields are parallel to the NW, ensuring their effective couplings.

We then study NW’s mode coupling by scanning it along the PPC lattice’s M – K direction. Similar as the discussions for the case of NW scanned along the $\Gamma$ – M direction, we plot the variations of $\Sigma P_y$, $\Delta \lambda$, $Q$, $V_{\text{mode}}$, and $\eta Q/V_{\text{mode}}$ when the NW locates at different $y$-positions, as shown in Figs. 3(a) and (b). The special NW-positions with inflections of parameters are marked by the dark dashed lines at $y = 0$ nm, 160 nm, 280 nm, and 560 nm. The mode’s intensity profiles and polarizations of electrical fields at these positions are displayed in Figs. 3(c1)-(c4), which could be used to explain the variations in Figs. 3(a) and (b).
Fig. 3. Simulation results when the NW scans along lattice’s M – K direction. (a) $\Delta P_y$, $\Delta \lambda$, and $\eta$ of the NW-PPC nanocavity versus NW’s position. (b) $Q$ factor, $V_{mode}$, and $\eta Q/V_{mode}$ of the NW-PPC nanocavity versus NW’s position, where the red dashed line indicates $Q_0$ factor and $V_{mode}$ of the bare nanocavity. (c-f) Mode’s intensity profiles and polarizations of electrical fields when the NW locates at $y = 0$ nm (c1), 160 nm (c2), 280 nm (c3) and 560 nm (c4), respectively.

The position-dependent $\Delta P_y$ of the bare PPC nanocavity shows the optical power is strongest at the cavity’s center ($y = 0$ nm). However, the $\Delta \lambda$ and $\eta$ of the NW-PPC nanocavities indicate that the strongest mode-NW coupling happens when the NW locates at $y = 280$ nm. It could be explained from the mode’s electrical field distributions shown in Figs. 3(c1)-(c4). When the NW locates at the cavity’s center, most of the mode’s electrical fields are perpendicular to the NW, which significantly hinders their coupling and forms a valley bottom of $\eta$ (bottom panel of Fig. 3(a)). However, the $\Delta \lambda$ is not a valley bottom (middle panel of the Fig. 3(a)), implying that the NW perturbs the cavity mode strongly at the cavity’s center. In the middle panel of Fig. 3(b), there is a dip of the $V_{mode}$ at $y = 0$ nm. It implies, while the NW-integration shifts the resonant wavelength strength, most of the mode-perturbation shapes the mode into the air around the NW, which is consistent with the weak mode-NW coupling due to the perpendicular electrical field. At $y = 280$ nm, the electrical fields are parallel to the NW, as shown in Fig. 3(c3), which therefore couple with the NW effectively.

The NW-PPC nanocavity has the maximum $Q$ factor when the NW locates at the cavity’s center, which actually approaches that in the bare PPC nanocavity. This non-degraded $Q$ factor could be attributed to the weak mode-NW coupling as well as the mode symmetry maintained by the central NW-integration, which is similar as that for the centrally located NW shown in Fig. 1. Comparing to the case of NW scanned along the $\Gamma$ – $M$ direction, when the NW scans along the $M$ – $K$ direction around the cavity’s center, the degradation of the $Q$ factor is not very sudden, and the mode coupling efficiency $\eta$ is lower. Even for the positions that $\eta$ is maximum, the decreased $Q$ factor still has values around 1,800, which promises a variety of important applications relying on mode’s narrow linewidth. Hence, scanning a NW along the cavity’s $M$ – $K$ direction has a larger tolerance on the position around the cavity center, which also support more efficient mode-couplings over a broad spectral range. In addition, the NW scanning along the $M$ – $K$ direction generates less variations over the $V_{mode}$, which is in a range of 0.213$(\lambda/n)^3$ to 0.229$(\lambda/n)^3$, as shown in the middle panel of Fig. 3(b). We also plot the $\eta Q/V_{mode}$ in the bottom panel of Fig. 3(b) to present the position-dependent light-NW interaction. Comparing to the corresponding results shown in Fig. 1(d), for the same resonant mode, the value of $\eta Q/V_{mode}$ in the configuration of a NW orientating along the $\Gamma$ – $M$ direction is much higher, and the maximum values almost flatly distribute over a spatial range about 200 nm. More importantly, the $Q$ factor maintains large detectable values over this wide spatial range, i.e., simultaneously promising high spectral resolutions in the NW-based devices.

Fig. 4. Simulation results of coupling between NW and cavity’s second-order mode. (a) Mode’s intensity profile (top panel) and polarizations (bottom panel) of the cavity’s second-order mode. (b,c) $\Delta \lambda$, $Q$ factor, $\eta$, and $\eta Q/V_{mode}$ of the second-order mode versus NW-position when it is scanned along $\Gamma$ – $M$ (b) and $M$ – $K$ (c) directions. The red dashed line indicates $Q_0$ factor of the bare nanocavity.

The employed H0 PPC nanocavity has high-order resonant modes, which could also be employed to enhance light-NW interaction. As a representative, we herein present the mode coupling of a scanned NW with the cavity’s second-order resonant mode, as shown in Fig. 4. The second-order resonant mode usually has a far-field electrical field component perpendicular to that of the fundamental resonant mode[24], and it owns higher $Q$ factors for applications of high-performance sensors[25]. In the simulation model, the NW and PPC nanocavity have the same parameters as those in the above section. The intensity profile and polarizations of the electrical fields for the second-order mode of the bare PPC nanocavity are shown in Fig. 4(a), which has the resonant wavelength of $\lambda_0 = 1,502.0$ nm, $Q_0 = 8,300$, and $V_{mode} = 0.214 (\lambda_0/n)^3$. When the NW scans along the $\Gamma$ – $M$ and $M$ – $K$ directions, the varied figures of merit of the second-order mode are plotted in Figs. 4(b) and (c), respectively. Similar as the discussions for the fundamental mode,
the variations of $\Delta \lambda$, $Q$, $\eta$, and $\eta Q/V_{mode}$ could be understood from the optical power distributions and electrical field directions of the mode overlapped with the NW. Specifically, the maximum $\Delta \lambda$ is about 15.5 nm.

For the two cases of NW scanned along the $\Gamma$ – $M$ and $M$ – $K$ directions, $\eta Q/V_{mode}$, which determines the strength of light-NW interaction, is maximum when the NW locates around the cavity’s center for the former. Whereas, for the latter situation, the maximum light-NW interaction happens when the NW locates at the cavity’s boundary on account of ultra-low $Q$ factor. Hence, when couple a NW with the second-order mode of the PPC nanocavity, it is preferred to locate the NW orientating along the $\Gamma$ – $M$ direction on the cavity’s center, which could provide the strongest light-NW interaction and maintain the high $Q$ factor with a large position tolerance. This characteristic is opposite to that obtained when the scanned NW couples with the fundamental mode (shown in Figs. 1 and 3).

![Fig. 5. Experiment results of mode-couplings in NW-PPC nanocavities when moving the NW along lattice’s $M$ – $K$ direction. (a) AFM images of the NW-PPC nanocavities when the $A_{0.2}G_{0.8}$As NW is moved gradually close to the cavity center. The scale bar corresponds to 500 nm. (b) The measured (dotted lines) and Lorentzian fitted (solid lines) reflect spectra of the fundamental (b1) and second-order (b2) resonant modes of the NW-PPC nanocavities with different NW-positions. (c) $\Delta \lambda$ of the fundamental (c1) and second-order (c2) modes versus NW-positions. (d) $Q$ factors of the fundamental (d1) and second-order (d2) modes versus NW-positions, where the black (red) dashed lines represent the simulated (measured) $Q_0$ factor.

To validate the above simulation results, we experimentally slide a NW across a PPC nanocavity and monitor its modification on the resonant modes. The PPC nanocavity is fabricated in a silicon-on-insulator wafer with a 220 nm thick top silicon layer [22]. With the combination of electron beam lithography, inductively coupled plasma dry etching, and wet chemical undercutting, air-suspended PPC nanocavity is obtained, which is designed with the parameters used in the above simulations. An $A_{0.2}G_{0.8}$As NW is employed to deposit onto the PPC nanocavity with an atomic force microscopy (AFM) technique [15]. The NW is pushed by the AFM-tip precisely to certain positions with the monitoring of the whole AFM scanning image. By the above, for the fundamental (second-order) resonant mode, scanning a NW along the $M$ – $K$ ($\Gamma$ – $M$) direction is preferred, we here just move the NW along $M$ – $K$ direction in order to experimentally verifying the mode-coupling. Figure 5(a) shows AFM images during the NW moves to different positions of the PPC nanocavity along the $M$ – $K$ direction. The first position of the NW is about 700 nm away from the cavity’s center, which is then successfully moved to 560 nm, 400 nm, 300 nm, 260 nm, 120 nm, and 20 nm, respectively. From the profiles of the AFM images, the diameter of the NW is measured as 120 nm and its length is about 6.4 $\mu$m.

The resonant modes of the bare and NW-PPC nanocavities are experimentally measured using a vertical microscope setup [20]. A tunable narrowband laser is employed as the excitation source, and the scattering signal from the nanocavity is measured by a photodiode, which gives rise to scattering spectrum by tuning the laser’s wavelength. A cross-polarization configuration of the excitation light and scattering signal is used to improve the signal to noise ratio of the resonant mode. Resonant modes would represent as narrowband peaks in the scattering spectra. Figures 5(b1) and (b2) show the acquired scattering peaks for the fundamental and second-order resonant modes from the NW-PPC nanocavities shown in Fig. 5(a). By fitting these peaks with Lorentzian functions, the $\lambda$s and $Q$ factors of the resonant modes are extracted. For the bare PPC nanocavity, the $\lambda$s ($Q$ factors) of the two resonant modes are $\lambda_0=1535.58$ nm ($Q_0=2,700$) and $\lambda_0=1485.72$ nm ($Q_0=3,100$), respectively. Due to the imperfections of the device fabrication, the $\lambda$s and $Q$ factors derive from the above simulation results. Comparing to the original $\lambda$s and $Q$ factors, we plot their variations versus the NW’s positions, as shown in Figs. 5(c) and (d). The corresponding simulation results are plotted as well. The variation trends of the $\lambda$s and $Q$ factors both have good agreements between the experiment and simulation results, which confirms the modes-NW coupling behaviors discussed above.

In conclusion, we demonstrate the mode-couplings between a NW and resonant modes of a PPC nanocavity by scanning the NW across over the cavity along the lattice’s $\Gamma$ – $M$ and $M$ – $K$ directions. The variations of $\lambda$, $Q$ factor, $\eta$ of the NW-PPC nanocavity are discussed carefully by referring to the cavity’s mode distribution and polarization of the electrical fields, which imply the optimal NW-positions for strong mode-NW couplings and light-NW interactions. For the fundamental (second-order) resonant mode, scanning a NW along the $M$ – $K$ ($\Gamma$ – $M$) direction is preferred, which supports stronger light-NW interactions when the NW locates over the cavity’s center. And the NW’s position has large tolerance for the device integration. Simultaneously, the high $Q$ factor could be maintained against the breaking of the
total internal reflection. Semiconductor NWs’ unique optical and electrical properties endow them have advantages in photodetection, modulation, light emission. Their mature growth and integration techniques make it possible to construct NW-PPC nanocavity for enhance light-NW interactions. Our work could provide consultation for constructing NW-PPC nanocavity devices to enhance light-NW interactions and improve NW-based optoelectronic devices.

This work was supported by the Financial support was provided by the Key Research and Development Program (Grant No. 2017YFA0303800), the NSFC (Grant Nos. 61522507, 61775183, 11634010), the Key Research and Development Program in Shaanxi Province of China (2017KJXX-12), the Academy of Finland (Grant Nos. 276376, 284548, 295777, 304666, 312297, 312551, and 314810), TEKES Academy of Finland (Grant Nos. 276376, 284548, 312297, 312551, and 314810), and the Key Research and Development Program in Shaanxi Province of China (Grant No.631610). We would like to thank the provision of technical facilities of the Micronova, the Analytical & Testing Center of NPU for the assistance of device fabrication; Aalto Centre of Quantum Engineering, China Scholarship Council, and the Analytical & Testing Center of NPU for the assistance of device fabrication; Aalto Centre of Quantum Engineering, China Scholarship Council, and the provision of technical facilities of the Micronova, Nanofabrication Centre of Aalto University.

Reference
